

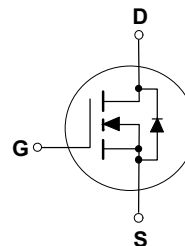
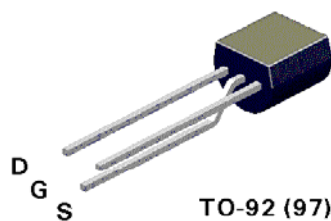
BS270 N-Channel Enhancement Mode Field Effect Transistor

General Description

These N-Channel enhancement mode field effect transistors are produced using Fairchild's proprietary, high cell density, DMOS technology. These products have been designed to minimize on-state resistance while provide rugged, reliable, and fast switching performance. They can be used in most applications requiring up to 500mA DC. These products are particularly suited for low voltage, low current applications such as small servo motor control, power MOSFET gate drivers, and other switching applications.

Features

- 400mA, 60V. $R_{DS(ON)} = 2\Omega @ V_{GS} = 10V$.
- High density cell design for low $R_{DS(ON)}$.
- Voltage controlled small signal switch.
- Rugged and reliable.
- High saturation current capability.



Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	BS270	Units
V_{DSS}	Drain-Source Voltage	60	V
V_{DGR}	Drain-Gate Voltage ($R_{GS} \leq 1M\Omega$)	60	V
V_{GSS}	Gate-Source Voltage - Continuous - Non Repetitive ($t_p < 50\mu s$)	± 20	V
		± 40	
I_D	Drain Current - Continuous - Pulsed	400	mA
		2000	
P_D	Maximum Power Dissipation Derate Above 25°C	625	mW
		5	mW/ $^\circ\text{C}$
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_L	Maximum Lead Temperature for Soldering Purposes, 1/16" from Case for 10 Seconds	300	$^\circ\text{C}$

THERMAL CHARACTERISTICS

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	200	$^\circ\text{C/W}$
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Electrical Characteristics (T _A = 25°C unless otherwise noted)						
Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 10 μA	60			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 60 V, V _{GS} = 0 V			1	μA
		T _J = 125°C			500	μA
I _{GSSF}	Gate - Body Leakage, Forward	V _{GS} = 20 V, V _{DS} = 0 V			10	nA
I _{GSSF}	Gate - Body Leakage, Reverse	V _{GS} = -20 V, V _{DS} = 0 V			-10	nA
ON CHARACTERISTICS (Note 1)						
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA	1	2.1	2.5	V
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 500 mA		1.2	2	Ω
		T _J = 125°C		2	3.5	
		V _{GS} = 4.5 V, I _D = 75 mA		1.8	3	
V _{DS(ON)}	Drain-Source On-Voltage	V _{GS} = 10 V, I _D = 500 mA		0.6	1	V
		V _{GS} = 4.5 V, I _D = 75 mA		0.14	0.225	
I _{D(ON)}	On-State Drain Current	V _{GS} = 10 V, V _{DS} ≥ 2 V _{DS(ON)}	2000	2700		mA
		V _{GS} = 4.5 V, V _{DS} ≥ 2 V _{DS(ON)}	400	600		
g _{FS}	Forward Transconductance	V _{DS} ≥ 2 V _{DS(ON)} , I _D = 200 mA	100	320		mS
DYNAMIC CHARACTERISTICS						
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		20	50	pF
C _{oss}	Output Capacitance			11	25	pF
C _{rss}	Reverse Transfer Capacitance			4	5	pF
SWITCHING CHARACTERISTICS (Note 1)						
t _{on}	Turn-On Time	V _{DD} = 30 V, I _D = 500 m A,			10	ns
t _{off}	Turn-Off Time	V _{GS} = 10 V, R _{GEN} = 25 Ω			10	
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
I _S	Maximum Continuous Drain-Source Diode Forward Current				400	mA
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				2000	mA
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 400 mA (Note 1)		0.88	1.2	V
Note: 1. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%.						

Typical Electrical Characteristics

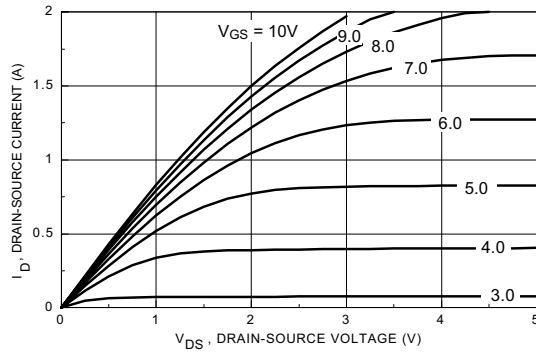


Figure 1. On-Region Characteristics.

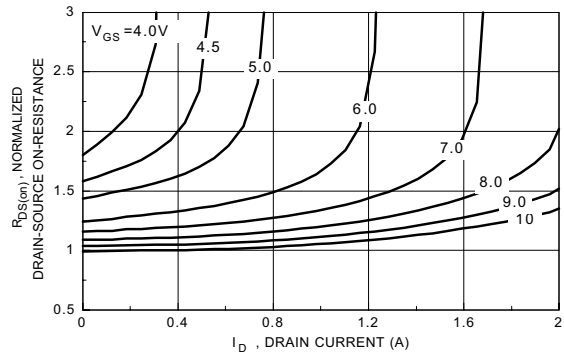


Figure 2. On-Resistance Variation with Gate Voltage and Drain Current.

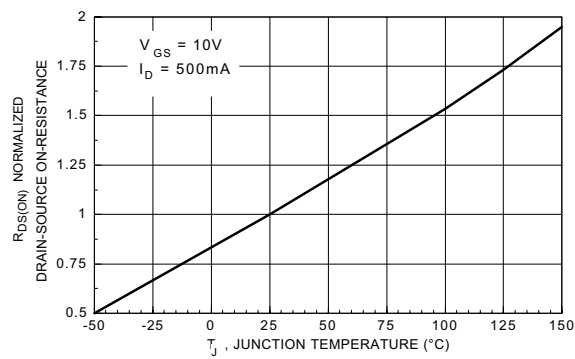


Figure 3. On-Resistance Variation with Temperature.

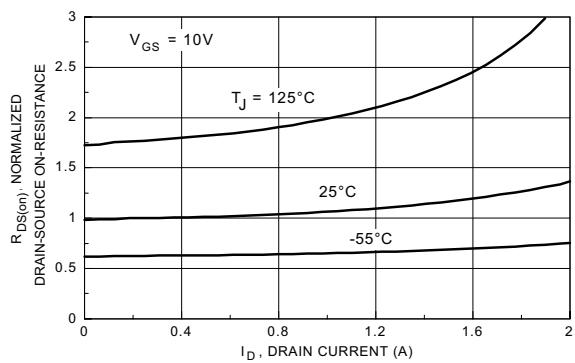


Figure 4. On-Resistance Variation with Drain Current and Temperature.

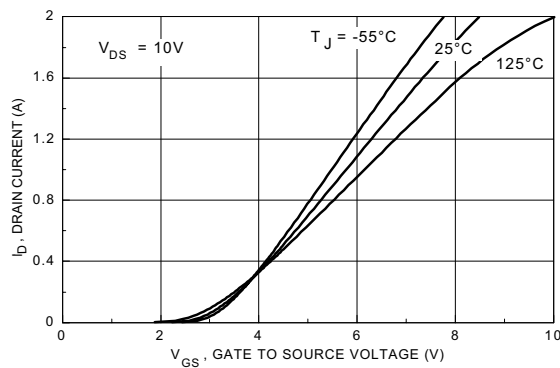


Figure 5. Transfer Characteristics.

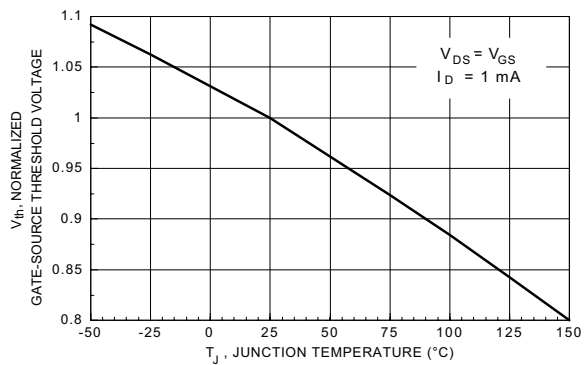


Figure 6. Gate Threshold Variation with Temperature.

Typical Electrical Characteristics (continued)

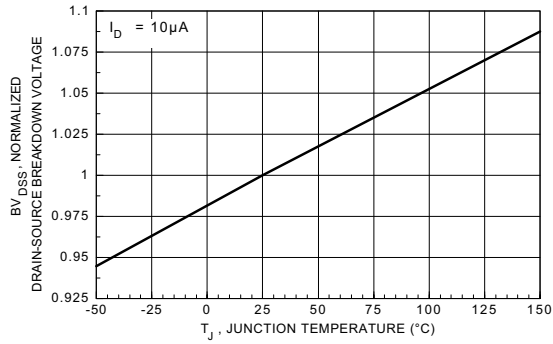


Figure 7. Breakdown Voltage Variation with Temperature.

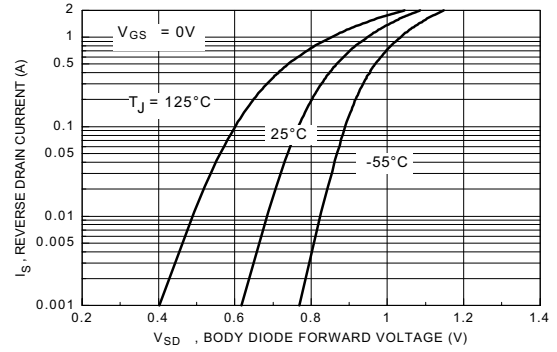


Figure 8. Body Diode Forward Voltage Variation with Current and Temperature.

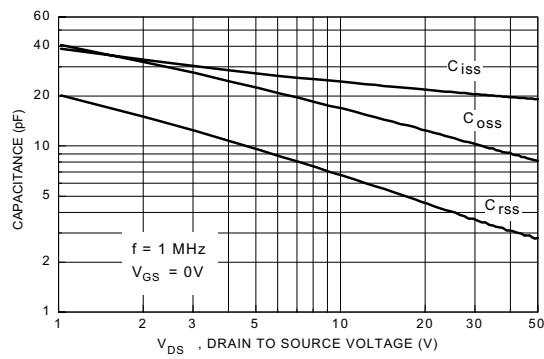


Figure 9. Capacitance Characteristics.

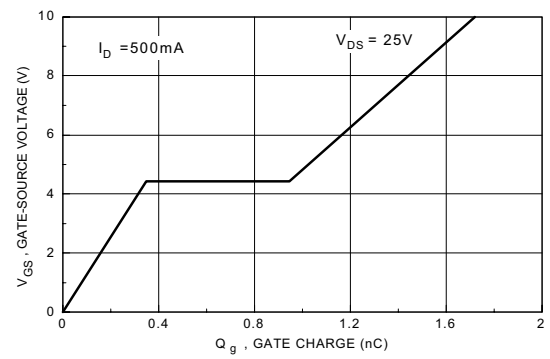


Figure 10. Gate Charge Characteristics.

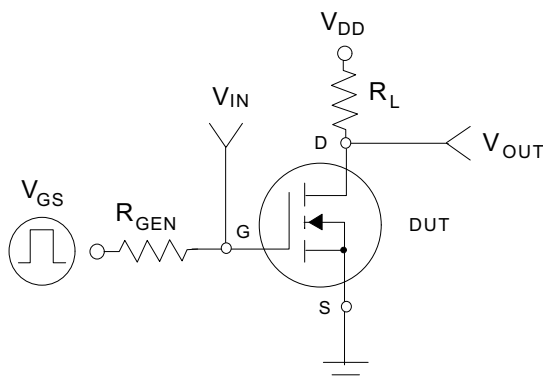


Figure 11. Switching Test Circuit.

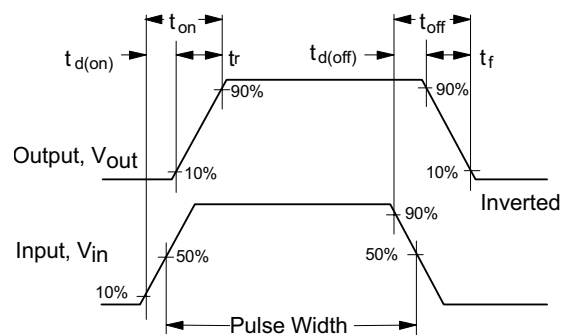


Figure 12. Switching Waveforms.

Typical Electrical Characteristics (continued)

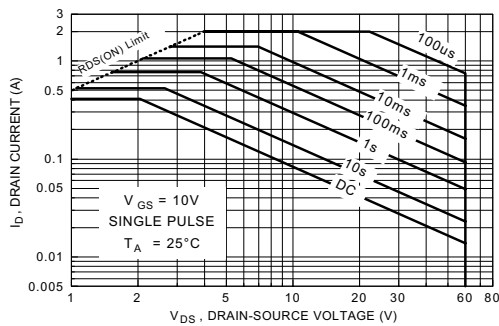


Figure 13. Maximum Safe Operating Area.

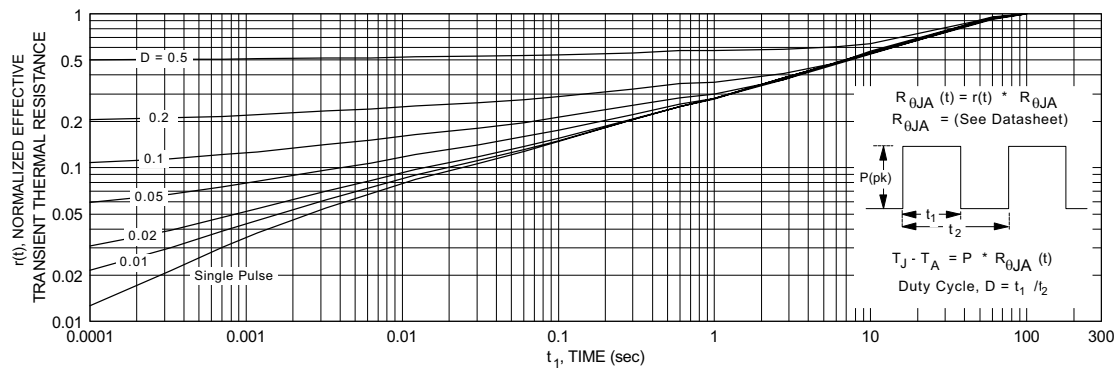


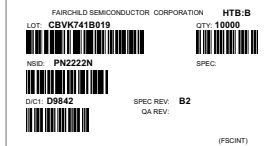
Figure 14. Transient Thermal Response Curve.

TO-92 Tape and Reel Data and Package Dimensions

TO-92 Packaging

Configuration: Figure 1.0

FSCINT Label sample

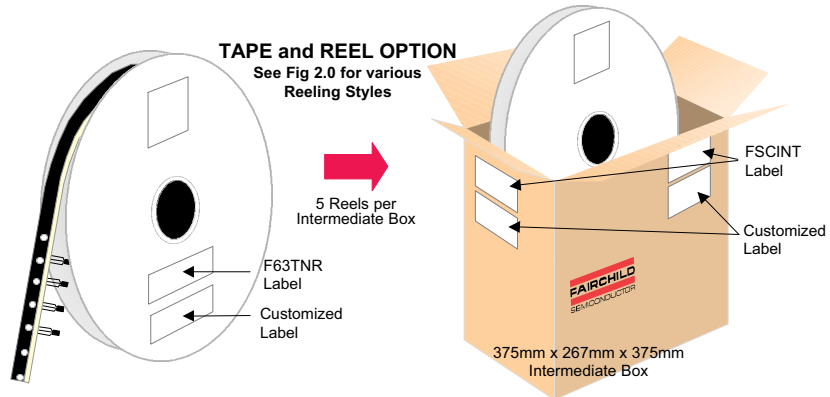


F63TNR Label sample



TAPE and REEL OPTION

See Fig 2.0 for various Reeling Styles



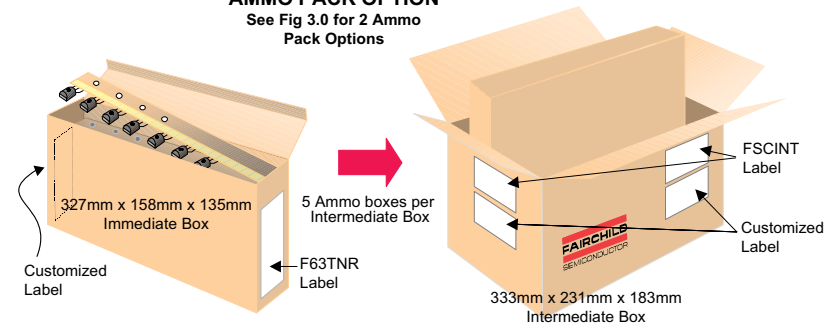
TO-92 TNR/AMMO PACKING INFORMATION

Packing	Style	Quantity	EOL code
Reel	A	2,000	D26Z
	B	2,000	D11Z
	C	2,000	D28Z
	D	2,000	D10Z
	E	2,000	D27Z
	F	2,000	D81Z
	G	2,000	D29Z
	H	2,000	D89Z
Ammo	M	2,000	D74Z
	P	2,000	D75Z

Unit weight = 0.22 gm
 Reel weight with components = 1.04 kg
 Ammo weight with components = 1.02 kg
 Max quantity per intermediate box = 10,000 units

AMMO PACK OPTION

See Fig 3.0 for 2 Ammo Pack Options

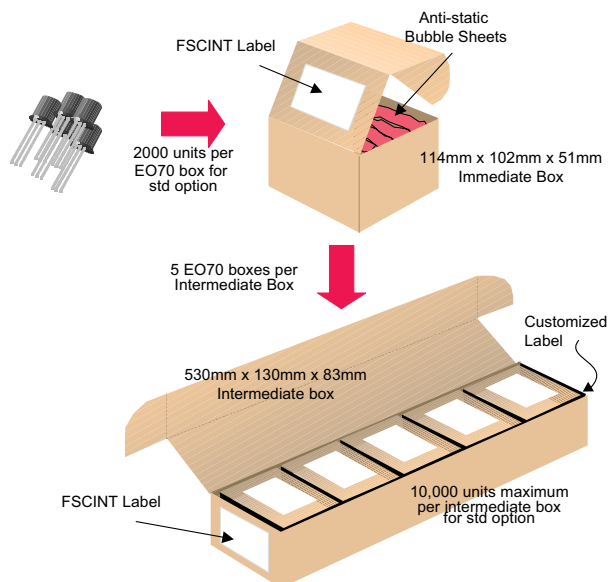


(TO-92) BULK PACKING INFORMATION

EOL CODE	DESCRIPTION	LEADCLIP DIMENSION	QUANTITY
J18Z	TO-18 OPTION STD	NO LEAD CLIP	2.0 K / BOX
J22Z	TO-18 OPTION STD	0.120 " - 0.150 "	3.5 K / BOX
J14Z	TO-18 OPTION STD	0.150 " - 0.180 "	3.0 K / BOX
J35Z	TO-18 OPTION REVERSE	NO LEAD CLIP	2.0 K / BOX
NO EOL CODE	TO-18 OPTION REVERSE	0.120 " - 0.150 "	3.5 K / BOX
NO EOL CODE	TO-18 OPTION REVERSE	0.150 " - 0.180 "	3.0 K / BOX
J05Z	TO-5 OPTION STD	NO LEAD CLIP	1.5 K / BOX
J24Z	TO-5 OPTION STD	0.120 " - 0.150 "	3.5 K / BOX
J25Z	TO-5 OPTION STD	0.150 " - 0.180 "	3.0 K / BOX
J60Z	TO-5 OPTION REVERSE	NO LEAD CLIP	1.5 K / BOX
J59Z	TO-5 OPTION REVERSE	0.120 " - 0.150 "	3.5 K / BOX
NO EOL CODE	TO-5 OPTION REVERSE	0.150 " - 0.180 "	3.0 K / BOX
J61Z	IN LINE 0.200 SPACING	NO LEADCLIP	1.5 K / BOX
NO EOL CODE	TO-92 STANDARD STRAIGHT	NO LEADCLIP	2.0 K / BOX
L34Z	STRAIGHT LEAD/NO CLIP/LF (FOR PKG 97 AND 98)	NO LEADCLIP	2.0 K / BOX
NO EOL CODE	EMITTER LEAD CUT	0.028 " MAX LEAD CUT	2.0 K / BOX
J21Z	CENTER LEAD CUT	0.028 " MAX LEAD CUT	2.0 K / BOX
J05A	MICROSOFT LEADFORM REQ'T	NO LEADCLIP	1.5 K / BOX
J05B	MICROSOFT LEADFORM REQ'T	0.120 " - 0.150 "	1.5 K / BOX
J05C	MICROSOFT LEADFORM REQ'T	0.150 " - 0.180 "	1.5 K / BOX

BULK OPTION

See Bulk Packing Information table

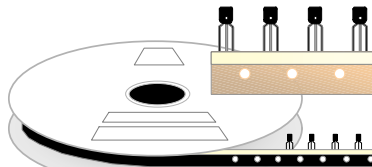


TO-92 Tape and Reel Data and Package Dimensions, continued

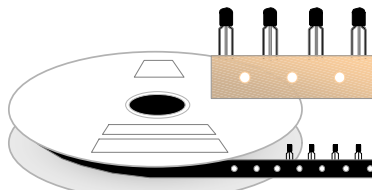
TO-92 Reeling Style

Configuration: Figure 2.0

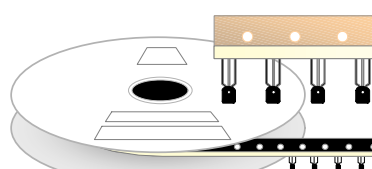
Machine Option "A" (H)



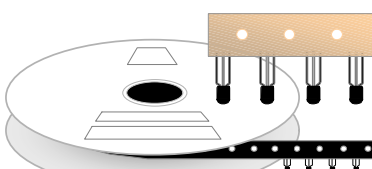
Style "A", D26Z, D70Z (s/h)



Style "B", D11Z

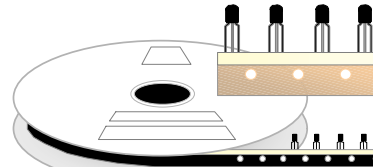


Style "C", D28Z, D72Z (s/h)

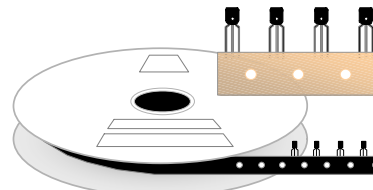


Style "D", D10Z

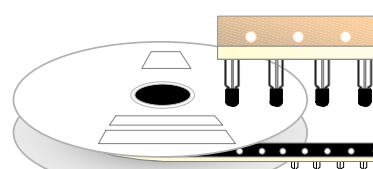
Machine Option "E" (J)



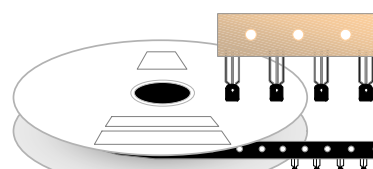
Style "E", D27Z, D71Z (s/h)



Style "F", D81Z



Style "G", D29Z, D73Z (s/h)

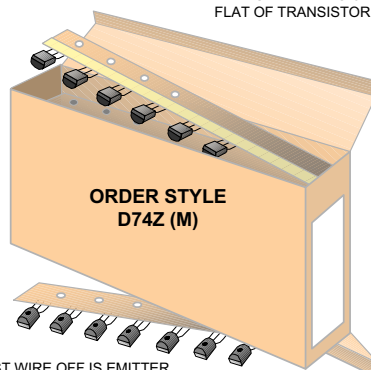


Style "H", D89Z

TO-92 Radial Ammo Packaging

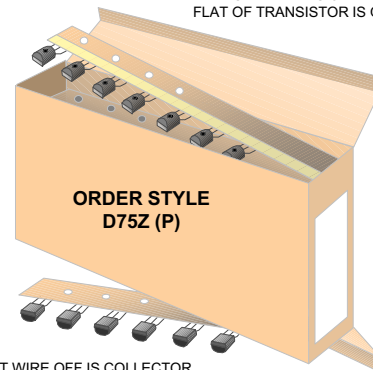
Configuration: Figure 3.0

FIRST WIRE OFF IS COLLECTOR
ADHESIVE TAPE IS ON THE TOP SIDE
FLAT OF TRANSISTOR IS ON TOP



FIRST WIRE OFF IS EMITTER
ADHESIVE TAPE IS ON BOTTOM SIDE
FLAT OF TRANSISTOR IS ON BOTTOM

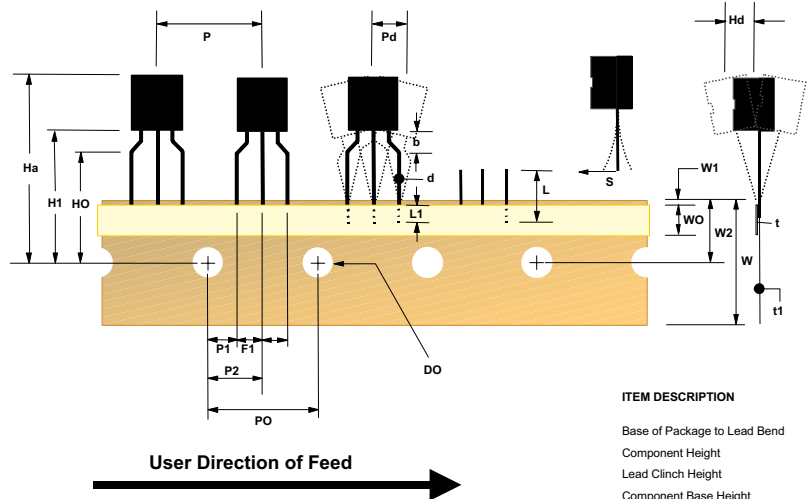
FIRST WIRE OFF IS EMITTER
ADHESIVE TAPE IS ON THE TOP SIDE
FLAT OF TRANSISTOR IS ON BOTTOM



FIRST WIRE OFF IS COLLECTOR
ADHESIVE TAPE IS ON BOTTOM SIDE
FLAT OF TRANSISTOR IS ON TOP

TO-92 Tape and Reel Data and Package Dimensions, continued

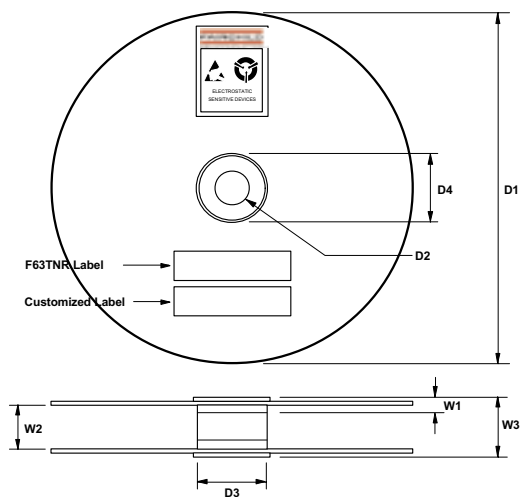
TO-92 Tape and Reel Taping
Dimension Configuration: Figure 4.0



ITEM DESCRIPTION	SYMBOL	DIMENSION
Base of Package to Lead Bend	b	0.098 (max)
Component Height	Ha	0.928 (+/- 0.025)
Lead Clinch Height	HO	0.630 (+/- 0.020)
Component Base Height	H1	0.748 (+/- 0.020)
Component Alignment (side/side)	Pd	0.040 (max)
Component Alignment (front/back)	Hd	0.031 (max)
Component Pitch	P	0.500 (+/- 0.020)
Feed Hole Pitch	PO	0.500 (+/- 0.008)
Hole Center to First Lead	P1	0.150 (+0.009, -0.010)
Hole Center to Component Center	P2	0.247 (+/- 0.007)
Lead Spread	F1/F2	0.104 (+/- 0.010)
Lead Thickness	d	0.018 (+0.002, -0.003)
Cut Lead Length	L	0.429 (max)
Taped Lead Length	L1	0.209 (+0.051, -0.052)
Taped Lead Thickness	t	0.032 (+/- 0.006)
Carrier Tape Thickness	t1	0.021 (+/- 0.006)
Carrier Tape Width	W	0.708 (+0.020, -0.019)
Hold - down Tape Width	WO	0.236 (+/- 0.012)
Hold - down Tape position	W1	0.035 (max)
Feed Hole Position	W2	0.360 (+/- 0.025)
Sprocket Hole Diameter	DO	0.157 (+0.008, -0.007)
Lead Spring Out	S	0.004 (max)

Note : All dimensions are in inches.

TO-92 Reel
Configuration: Figure 5.0

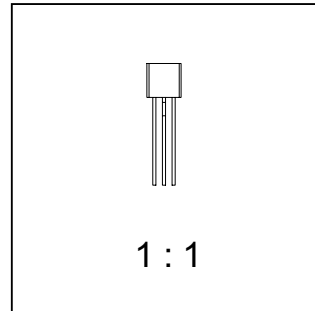
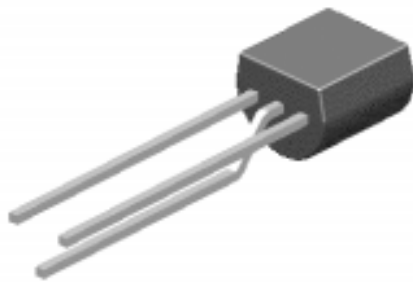


ITEM DESCRIPTION	SYMBOL	MINIMUM	MAXIMUM
Reel Diameter	D1	13.975	14.025
Arbor Hole Diameter (Standard)	D2	1.160	1.200
(Small Hole)	D2	0.650	0.700
Core Diameter	D3	3.100	3.300
Hub Recess Inner Diameter	D4	2.700	3.100
Hub Recess Depth	W1	0.370	0.570
Flange to Flange Inner Width	W2	1.630	1.690
Hub to Hub Center Width	W3		2.090

Note: All dimensions are inches

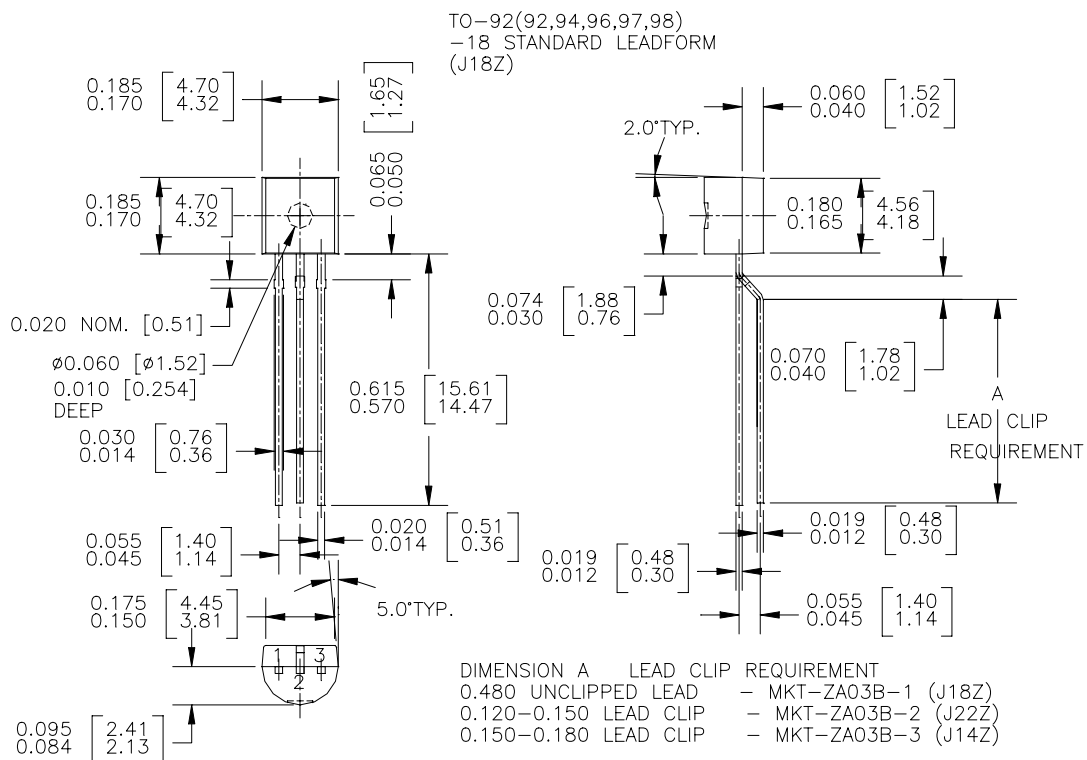
TO-92 Tape and Reel Data and Package Dimensions, continued

TO-92; TO-18 Lead Form STD (FS PKG Code 97)



Scale 1:1 on letter size paper

Part Weight per unit (gram): 0.2201



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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.